1 General description

The TFA9874B is a high efficiency 10.0 V boosted class-D audio amplifier. It can deliver up to 10.0 W peak output power into an 8 Ω speaker and up to 11.8 W peak output power into a 6 Ω speaker, at a supply voltage of 4.0 V. The internal adaptive DC-to-DC converter raises the supply voltage up to 10.0 V, providing ample headroom for major improvements in sound quality.

Internal adaptive DC-to-DC conversion boosts the supply rail to provide additional headroom and power output. The supply voltage is only raised when necessary. This maximizes the output power of the class-D audio amplifier while limiting quiescent power consumption.

The device can be configured to drive either a hands-free speaker (4 Ω to 8 Ω) for audio playback, or a receiver speaker (32 Ω), for handset playback, allowing it to be embedded in platforms supporting both a hands-free speaker and a handset speaker. The maximum output power and the noise levels are lower in handset call use case than in hands-free call use case.

The TFA9874B also incorporates battery protection. By limiting the supply current when the battery voltage is low, it prevents the audio system from drawing excessive load currents from the battery, which could cause a system under voltage. This circuitry minimizes the impact of a falling battery voltage by preventing unexpected device switch off due to excessive current drawn from the battery.

The device features low RF susceptibility because it has a digital input interface that is insensitive to clock jitter. The second order closed loop architecture used in a class-D audio amplifier provides excellent audio performance and high supply voltage ripple rejection. The audio input interface is TDM and the control settings are communicated via an l^2 C-bus interface.

The TFA9874B is available in a 36-bump WLCSP (Wafer Level Chip-Size Package) with a 400 μm pitch.

2 Features and benefits

- High output power: 5.6 W (average) into 8 Ω at 4.0 V supply voltage (THD = 1 %)
- + Supports handset (16 Ω or 32 $\Omega)$ and hands-free (4 Ω to 8 $\Omega) speaker configurations$
- High efficiency, low power dissipation and low-noise speaker driver
- Adaptive DC-to-DC converter increases the supply voltage smoothly when switching between Fixed Boost and Adaptive Boost modes, preventing large battery supply spikes and limiting quiescent power consumption
- Wide supply voltage range (fully operational from 2.7 V to 5.5 V)
- Very low noise output voltage <15 μ V (with -60 dBFS input at f_s = 48 kHz)
- Low battery current consumption <125 mA (P_o = 380 mW, average music power)
- I²C-bus control interface (400 kHz)



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- Speaker current and voltage monitoring (via the TDM-bus) for Acoustic Echo Cancellation (AEC) at the host
- 16 kHz/32 kHz/44.1 kHz/48 kHz sample frequencies supported
- Ultrasonic support via TDM running at 96 kHz
- · Programmable interrupt control via a dedicated interrupt pin
- · Low RF susceptibility
- Thermal foldback and overtemperature protection
- · 15 kV system-level ESD protection without external components on amplifier output

3 Applications

- Mobile phones and Tablets
- Portable Navigation Devices (PND)
- Notebooks/Netbooks
- · Internet of Things applications embedding high quality audio

4 Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{BAT}	battery supply voltage	on pin VBAT V_{BAT} must not be lower than V_{DDD} in application	2.7	-	5.5	V
V _{DDD}	digital supply voltage	on pin VDDD	1.65	1.8	1.95	V
V _{DDP}	power supply voltage	on pin VDDP	2.7	-	10.0	V
RL	load resistance		3.2	-	38	Ω
I _{BAT}	battery supply current	Active state on pin VBAT; Operating mode with load $R_L = 6 \Omega$; DC-to-DC in Adaptive Boost mode, $P_0 = 380 \text{ mW}$, (average music power), V _{BAT} = 4.0 V, V _{BST} = 10 V	-	120	-	mA
		Idle state on pin VBAT; Operating mode with load $R_L = 6 \Omega$; DC-to-DC in Adaptive Boost mode, $P_o = 0$ mW, $V_{BAT} = 4.0$ V, $V_{BST} =$ 10 V	-	2.5	-	mA
		Power-down state	-	1	-	μA
I _{DDD}	digital supply current	Active state on pin VDDD; Operating mode with load $R_L = 6 \Omega$; DC-to-DC in Adaptive Boost mode, $P_0 = 380 \text{ mW}$, (average music power), $V_{BAT} = 4.0 \text{ V}$, $V_{BST} = 10 \text{ V}$	-	5.2	-	mA
		Idle state on pin VDDD; Operating mode with load $R_L = 6 \Omega$; DC-to-DC in Adaptive Boost mode, $P_o = 0$ mW, $V_{BAT} = 4.0$ V, $V_{BST} =$ 10 V	-	3.6	-	mA
		Power-down state	1.6	3	19	μA

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
P _{o(AV)}	average output power	THD+N = 1 %; (R _L = 8 Ω; L _L = 44 μH); V _{BST} 10.0 V; V _{BAT} = 4.0 V; V _{DDD} = 1.8 V	5.3	5.6	-	W
		THD+N = 1 %; (R _L = 6 Ω ; L _L = 32 μ H); V _{BST} = 10.0 V; V _{BAT} = 4.0 V; V _{DDD} = 1.8 V	5.8	6.1	-	W
		THD+N = 1 %; (R _L = 4 Ω ; L _L = 30 μ H); V _{BST} = 9.0 V; V _{BAT} = 4.0 V; V _{DDD} = 1.8 V	, 6	6.2	-	W

5 Ordering information

Table 2. Ordering information

Type number	Package						
	Name	Description	Version				
TFA9874UK/N1	WLCSP36	wafer level chip-scale package; 36 bumps; 2.62 mm x 2.51 mm x 0.5 mm body	SOT1780-5				
TFA9874BUK/N1	WLCSP36	wafer level chip-scale package; 36 bumps; 2.62 mm x 2.51 mm x 0.525 mm body (backside coating included)	SOT1780-4				

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6 Block diagram



7 Pinning information

7.1 Pinning



	1	2	3	4	5	6
А	BCK	FS	VDDD	SCL	SDA	TRSTN
В	DATAO	DATAI	ADS2	ADS1	INT	VBAT
С	RST	GNDD	VSN	TEST2	TEST1	VSP
D	GNDB	GNDB	GNDB	GNDD	GNDP	GNDD
E	INB	INB	INB	OUTP	GNDP	OUTN
F	VBST	VBST	VBST	VDDP	VDDP	VDDP

aaa-030120

Transparent top view

Figure 3. Bump mapping

Table 3. Pinnir	ng		
Symbol	Pin	Туре	Description
BCK	A1	I	digital audio bit clock input for TDM interface
FS	A2	I	digital audio frame sync input for TDM interface
VDDD	A3	I	digital supply voltage
SCL	A4	I	digital I ² C-bus clock input
SDA	A5	I/O	digital I ² C-bus data input/output
TRSTN	A6	I	test signal input TRSTN, connect to PCB ground
DATAO	B1	I/O	digital audio data output for TDM interface
DATAI	B2	I	digital audio data input for TDM interface

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Symbol	Pin	Туре	Description
ADS2	B3	I	digital address select input 2
ADS1	B4	I	digital address select input 1
INT	B5	0	digital interrupt output
VBAT	B6	Р	battery supply voltage
RST	C1	I	reset input
GNDD	C2	Р	digital ground
VSN	C3	I/O	voltage sense negative input
TEST2	C4	I/O	test signal input 2; for test purposes only; connect to PCB ground, or connect via a capacitor to PCB ground
TEST1	C5	I/O	test signal input 1; for test purposes only; connect to PCB ground, or connect via a capacitor to PCB ground input
VSP	C6	I/O	voltage sense positive
GNDB	D1	Р	boosted ground
GNDB	D2	Р	boosted ground
GNDB	D3	Р	boosted ground
GNDD	D4	Р	digital ground
GNDP	D5	Р	power ground
GNDD	D6	Р	digital ground
INB	E1	Р	DC-to-DC boost converter input
INB	E2	Р	DC-to-DC boost converter input
INB	E3	Р	DC-to-DC boost converter input
OUTP	E4	0	non-inverting output
GNDP	E5	Р	power ground
OUTN	E6	0	inverting output
VBST	F1	0	boosted supply voltage output
VBST	F2	0	boosted supply voltage output
VBST	F3	0	boosted supply voltage output
VDDP	F4	Р	power supply voltage
VDDP	F5	Р	power supply voltage
VDDP	F6	Р	power supply voltage

8 Functional description

The TFA9874B is a highly efficient Bridge Tied Load (BTL) class-D audio amplifier as depicted in block diagram; see Figure 1.

TFA9874B contains a TDM input/output interface for communicating with the audio host. It also offers the possibility of providing an ultrasonic path to the speaker.

At low battery voltage levels, the gain (from TDM interface to speaker output) is automatically reduced to limit battery current (when battery safeguard is enabled).

The digital audio stream is converted into two Pulse Width Modulated (PWM) signals which are then injected into the class-D audio amplifier. The 3-level PWM scheme supports filterless speaker drive.

An adaptive DC-to-DC converter boosts the output voltage to the level that is required by the ClassD amplifier.

9 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{BAT}	battery supply voltage	on pin VBAT	-0.3	-	+6	V
V _{BST}	booster output voltage	on pin VBST	-0.3	-	+12 ^[1]	V
V _{INB}	booster input voltage	on pin INB	-0.3	-	+12 ^[1]	V
V _{DDP}	power supply voltage	on pin VDDP	-0.3	-	+12 ^[1]	V
Vo	output voltage	on speaker connections; pins OUTP, OUTN	-0.3	-	+12 ^[1]	V
V _{DDD}	digital supply voltage	on pin VDDD	-0.3	-	+2.5	V
V _{low}	low voltage	on pins TEST1/TEST2	-0.3	-	+2.5	V
Tj	junction temperature		-	-	+125	°C
T _{stg}	storage temperature		-55	-	+150	°C
T _{amb}	ambient temperature		-40	-	+85	°C
V _{ESD}	electrostatic discharge voltage	according to Human Body Model (HBM)	-2	-	+2	kV
		according to Charge Device Model (CDM)	-500	-	+500	V

[1] Using NXP demo board, with a 1 mm wire/PCB track length on INB pin, AC pulses between -6 V and +15 V can be observed without damaging the device, as these spikes do not end up inside the actual device.

10 Thermal characteristics

Table 5. T	hermal characteristics				
Symbol	Parameter	Conditions	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	4-layer application board	49	-	K/W

11 Characteristics

11.1 DC characteristics

Table 6. DC characteristics

All parameters are guaranteed for V_{BAT} = 3.6 V; V_{DDD} = 1.8 V; V_{DDP} = V_{BST} = 10.0 V, adaptive boost mode; L_{BST} = 1 $\mu H^{[1]}$; R_L = 8 $\Omega^{[1]}$; L_L = 44 $\mu H^{[1]}$; f_i = 1 kHz; f_s = 48 kHz; T_{amb} = 25 °C; default settings, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{BAT}	battery supply voltage	on pin VBAT		2.7	-	5.5	V
		V_{BAT} must not be lower than V_{DDD}					
I _{BAT}	battery supply current	Active state: On pin VBAT; Operating mode with load RL = 6Ω ; DC-to-DC in Adaptive Boost mode; P _o = 380 mW, (average music power), V _{BAT} = 4.0 V		-	120	-	mA
		Idle state: On pin VBAT; Operating mode with load RL = 6Ω and no output signal (idle); DC-to-DC converter in Adaptive Boost mode; V _{BAT} = 4.0 V		-	2.5	-	mA
		Power-down state: On pin VBAT; DC-to-DC in Power-down mode; $T_j = 25 \text{ °C}$; no clock		-	1	-	μA
V _{DDP}	power supply voltage	on pin VDDP		2.7	-	10.0	V
V _{DDD}	digital supply voltage	on pin VDDD		1.65	1.8	1.95	V
I _{DDD}	digital supply current	Active state		-	5.2	-	mA
		Idle state		-	3.6	-	mA
		Power-down state		1.6	3	19	μA
Pins FS, BC	CK, DATAI, ADS1, ADS2, SCL, SD	A, RST, TRSTN					_
V _{IH}	HIGH-level input voltage			0.7V _{DDD}	-	V _{DDD}	V
V _{IL}	LOW-level input voltage			-	-	$0.3V_{DDD}$	V
C _{in}	input capacitance		[2]	-	-	3	pF
ILI	input leakage current	1.8 V on input pin		-	-	0.1	μA
Pins DATA	O, INT, push-pull output stages	·					_
V _{OH}	HIGH-level output voltage			V _{DDD} - 0.4	-	-	V
V _{OL}	LOW-level output voltage			-	-	400	mV
Pins SDA, o	open-drain outputs, external 10 k	$\mathbf{\Omega}$ resistor to V _{DDD}		ļ.		1	
V _{OH}	HIGH-level output voltage			V _{DDD} - 0.4	-	-	V
V _{OL}	LOW-level output voltage	I _{OL} = 4 mA		-	-	400	mV
Pins OUTP	OUTN						
R _{DSon}	drain-source on-state resistance	PMOS+NMOS transistors		-	430	520	mΩ

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Protection					I		
T _{act(th_prot)}	thermal protection activation temperature			130	-	-	°C
V _{ovp(VBAT)}	overvoltage protection on pin VBAT			5.6	-	6.0	V
V _{uvp(VBAT)}	undervoltage protection on pin VBAT			2.3	-	2.7	V
I _{O(ocp)}	overcurrent protection output current			2.5	-	-	A
DC-to-DC	converter				1		
V _{BST}	voltage on pin VBST	DCVOS = 111111; Boost mode (after trim)	[3]	9.8	10	10.2	V

[1] L_{BST} = boost converter inductance; R_L = load resistance; L_L = load inductance (speaker).

[2] [3] This parameter is not tested during production; the value is guaranteed by design and checked during product validation. Boost switching frequency = 2 MHz in PWM mode.

11.2 AC characteristics

Table 7. AC characteristics

All parameters are guaranteed for V_{BAT} = 3.6 V; V_{DDD} = 1.8 V; V_{DDP} = V_{BST} = 10.0 V, adaptive boost mode; L_{BST} = 1 $\mu H^{[1]}$; R_L = 8 $\Omega^{[1]}$; L_L = 44 $\mu H^{[1]}$; f_i = 1 kHz; f_s = 48 kHz; T_{amb} = 25 °C; default settings, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
Amplifier ou	itput power	· · · · · · · · · · · · · · · · · · ·							
P _{o(AV)}	average output power	Hands-free speaker, THD+N = 1 %; \	I %; V _{DDD} = 1.8 V						
		R _L = 8 Ω; L _L = 44 μH; f _s = 48 kHz, V _{BST} = 10.0 V, V _{BAT} = 4.0 V	5.3	5.6	-	W			
		R _L = 6 Ω; L _L = 32 μH; f _s = 48 kHz, V _{BST} = 10.0 V, V _{BAT} = 4.0 V	5.8	6.1	-	W			
		R_L = 4 Ω; L_L = 30 μH; f_s = 48 kHz, V_{BST} = 9.0 V, V_{BAT} = 4.0 V	6	6.2	-	W			
		Receiver speaker; THD+N = 1 %; V _{BS}	_{ST} = 10.0 \	V					
		R_L = 32 Ω ; Voice mode	-	0.2	-	W			
		R_L = 32 Ω ; Audio mode	-	1.5	-	W			
Amplifier ou	Itput pins (OUTP and OUTN)								
V _O (offset)	output offset voltage	absolute value, after trimming; V _{DDP} = 3.4 V to 10.0 V, V _{BAT} = 3.4 V to 5 V	-	-	1.0	mV			

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Amplifier p	erformances						
η _{po}	output power efficiency	On pin VBAT; Operating mode with load $R_L = 6 \Omega$; DC-to-DC in Adaptive Boost mode, $P_o = 380$ mW, (average music power), $V_{BAT} = 4.0 V$	[2]		82	-	%
		On pin VBAT; input: 100 Hz sine wave, $R_L = 8 \Omega$; DC-to-DC in Tracking Boost mode, $V_{BAT} = 4.0 V$, $P_o = 600 \text{ mW}$	[2]	-	91	-	%
		On pin V _{BAT} ; Input: 100 Hz sine wave, R _L = 8 Ω ; DC-to-DC in Tracking Boost mode, V _{BAT} = 4.0 V, P _o = 4 W	[2]	-	84	-	%
THD+N	total harmonic distortion-plus-noise	V_{DDP} > 9 V, P _o = 2.0 W, RL = 8 Ω	[3]	-	-	0.05	%
		V_{DDP} > 9 V, P_o = 2.0 W, RL = 4 Ω	[3]	-	-	0.09	%
V _{n(o)}	output noise voltage	A-weighted; no input signal; Low Noise mode; f _s = 48 kHz	[2]	-	14	18	μV
		A-weighted; no input signal; Low Noise mode; f _s = 16 kHz, 32 kHz	[2]	-	-	50	μV
		A-weighted; no input signal; Low Noise mode; f _s = 44.1 kHz	[2]	-	15	18	
DR	dynamic range	A-weighted; V_{BAT} = 3.4 V to 5 V; S/ N = maximum signal (at THD = 1 %); output noise voltage ($V_{n(o)}$); NO signal applied	[2]	110	114	-	dB
S/N	signal-to-noise ratio	A-weighted, V_{BAT} = 3.4 V to 5 V, maximum signal at THD = 1 %	[2]	100	-	-	dB
PSRR	power supply rejection ratio	from V _{BAT;} booster in follower mode (V _{DDP} = V _{BAT}) f_{ripple} = 217 Hz square wave, V _{ripple} = 50 mV _(p-p) , V _{BAT} = 4.0 V		60	80	-	dB
		from V _{BAT;} booster in follower mode (V _{DDP} = V _{BAT}) f_{ripple} = 20 Hz to 1 kHz sine wave, V _{ripple} = 200 mV (RMS), V _{BAT} = 3.4 V to 5.0 V Low Power AND Low Noise modes		60	80	-	dB
		on					
		from V _{BAT} ; booster in follower mode (V _{DDP} = V _{BAT}) $f_{ripple} = 1 \text{ kHz}$ to 20 kHz sine wave, V _{ripple} = 200 mV (RMS), V _{BAT} = 3.4 V to 5.0 V		55	60	-	dB
∆G/∆f	gain variation with frequency	BW = 20 Hz to 15 kHz, V_{BAT} = 3.4 V to 5 V		-0.1	-	+0.7	dB
V _{POP}	pop noise voltage	At mode transition and gain change.		-	-	2	mV

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
RL	load resistance			3.2	8	38	Ω
CL	load capacitance			-	-	200	pF
f _{sw}	switching frequency	directly coupled to the TDM input frequency		256	-	384	kHz
G _(TDM-VO)	TDM to V _O gain	INPLEV = 0 dB		6	-	21	dB
Amplifier pov	wer-up, power-down and propagatio	on delays					
t _{d(on)PLL}	PLL turn-on delay time	PLL locked on BCK, $f_s = 48 \text{ kHz}$		-	2	-	ms
t _{d(on)amp}	amplifier turn-on delay time	f _s = 48 kHz		-	1	-	ms
t _{d(off)}	turn-off delay time			-	32	-	μs
t _{d(alarm)}	alarm delay time			-	200	-	ms
t _{PD}	propagation delay	Delta Propagation delay between L & R in stereo application = 1.625 FS					
		f _s = 16 kHz		-	-	850	μs
		f _s = 16 kHz HP		-	-	850	μs
		f _s = 32 kHz		-	-	750	μs
		f _s = 44.1 kHz		-	-	650	μs
		f _s = 48 kHz		-	-	700	μs
		f _s = 96 kHz		-	-	600	μs
Booster Indu	ctance					·	
L _{bst}	boost inductance			0.33	1.0	2.2	μH
Voltage and (Current-sensing performance						
S/N	signal-to-noise ratio	I _O = 1.1 A (peak); A-weighted		62	65	-	dB
			[4]		•		%
$\Delta V_{sense}/I_{sense}$	V _{sense} /I _{sense} ratio mismatch	Pilot tone -40 dBFS		-	2	-	70

[1]

 L_{BST} = boost converter inductance; R_L = load resistance; L_L = load inductance (speaker). This parameter is not tested during production; the value is guaranteed by design and checked during product validation. L_{BST} = boost converter inductor; R_L = load resistance; L_L = load inductance (speaker). Intended for Speaker protection. In combination with NXP Speaker protection a speaker temperature accuracy of ±10 °C can be realized. [2] [3] [4]

11.3 TDM timing characteristics

Table 8. TDM bus interface characteristics

All parameters are guaranteed for V_{BAT} = 3.6 V; V_{DDD} = 1.8 V; V_{DDP} = V_{BST} = 10.0 V, adaptive boost mode; L_{BST} = 1 $\mu H^{[1]}$; R_L = 8 $\Omega^{[1]}$; L_L = 44 $\mu H^{[1]}$; f_i = 1 kHz; f_s = 48 kHz; T_{amb} = 25 °C; default settings, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
f _s	sampling frequency	on pin WS, audio mode	[2]	16	-	48	kHz
		on pin WS, ultrasonic mode		-	-	96	kHz
f _{clk}	clock frequency	on pin BCK, audio mode	[2]	32f _s	-	384f _s	kHz
		on pin BCK, ultrasonic mode		-	-	96f _s	MHz
t _{su}	set-up time	WS edge to BCK HIGH	[3]	10	-	-	ns
		DATA edge to BCK HIGH		10	-	-	ns
t _h	hold time	BCK HIGH to WS edge	[3]	10	-	-	ns
		BCK HIGH to DATA edge		10	-	-	ns
tj	external clock jitter	PLL locked on BCK	[4]	-	1	2	ns
		PLL locked on FS	[5]	-	-	20	ns

[1]

 L_{BST} = boost converter inductance; R_L = load resistance; L_L = load inductance. The TDM bit clock input (BCK) is used as a clock input for the amplifier and the DC-to-DC converter. Note that both the BCK and WS signals need to be [2] The TDM bit clock input (BCK) is used as a clock input of the amplifier and the DC-to-DC converter. Note that both the DC target and the BCK and the B

[3] [4] [5]

The system is less sensitive to jitter when the PLL is locked on FS.



11.4 I²C timing characteristics

Table 9. I²C-bus interface characteristics; see Figure 15

All parameters are guaranteed for $V_{BAT} = 3.6 \text{ V}$; $V_{DDD} = 1.8 \text{ V}$; $V_{DDP} = V_{BST} = 10.0 \text{ V}$, adaptive boost mode; $L_{BST} = 1 \ \mu H^{[1]}$; $R_L = 8 \ \Omega^{[1]}$; $L_L = 44 \ \mu H^{[1]}$; $f_i = 1 \ kHz$; $f_s = 48 \ kHz$; $T_{amb} = 25 \ ^{\circ}\text{C}$; default settings, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
f _{SCL}	SCL clock frequency			-	-	400	kHz
t _{LOW}	LOW period of the SCL clock			1.3	-	-	μs
t _{HIGH}	HIGH period of the SCL clock			0.6	-	-	μs
t _r	rise time	SDA and SCL signals	[2]	20 + 0.1 C _b	-	-	ns
t _f	fall time	SDA and SCL signals	[2]	20 + 0.1 C _b	-	-	ns
t _{HD;STA}	hold time (repeated) START condition		[3]	0.6	-	-	μs
t _{SU;STA}	set-up time for a repeated START condition			0.6	-	-	μs
t _{su;sто}	set-up time for STOP condition			0.6	-	-	μs
t _{BUF}	bus free time between a STOP and START condition			1.3	-	-	μs
t _{SU;DAT}	data set-up time			100	-	-	ns
t _{HD;DAT}	data hold time			0	-	-	μs
t _{SP}	pulse width of spikes that must be suppressed by the input filter		[4]	0	-	50	ns
C _b	capacitive load for each bus line			-	-	400	pF

[1] [2] [3] [4]

 L_{BST} = boost converter inductance; R_L = load resistance; L_L = load inductance (speaker). C_b is the total capacitance of one bus line in pF. The maximum capacitive load for each bus line is 400 pF. After this period, the first clock pulse is generated. To be suppressed by the input filter.



12 Application information



12.1 Application diagrams

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13 Package outline



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14 Soldering of WLCSP packages

14.1 Introduction to soldering WLCSP packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering WLCSP (Wafer Level Chip-Size Packages) can be found in application note *AN10439 "Wafer Level Chip Scale Package"* and in application note *AN10365 "Surface mount reflow soldering description"*.

Wave soldering is not suitable for this package.

All NXP Semiconductors WLCSP packages are lead-free.

14.2 Board mounting

Board mounting of a WLCSP requires several steps:

- 1. Solder paste printing on the PCB
- 2. Component placement with a pick and place machine
- 3. The reflow soldering itself

14.3 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see Figure 10) than a SnPb process, thus reducing the process window
- Solder paste printing issues, such as smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature), and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic) while being low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with <u>Table 10</u>.

Package thickness (mm)	Package reflow temperature (°C)					
	Volume (mm ³)					
	< 350	350 to 2 000	> 2 000			
< 1.6	260	260	260			
1.6 to 2.5	260	250	245			
> 2.5	250	245	245			

Table 10. Lead-free process (from J-STD-020D)

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see <u>Figure 10</u>.

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For further information on temperature profiles, refer to application note AN10365 "Surface mount reflow soldering description".

14.3.1 Stand off

The stand off between the substrate and the chip is determined by:

- The amount of printed solder on the substrate
- The size of the solder land on the substrate
- · The bump height on the chip

The higher the stand off, the better the stresses are released due to TEC (Thermal Expansion Coefficient) differences between substrate and chip.

14.3.2 Quality of solder joint

A flip-chip joint is considered to be a good joint when the entire solder land has been wetted by the solder from the bump. The surface of the joint should be smooth and the shape symmetrical. The soldered joints on a chip should be uniform. Voids in the bumps after reflow can occur during the reflow process in bumps with high ratio of bump diameter to bump height, i.e. low bumps with large diameter. No failures have been found to be related to these voids. Solder joint inspection after reflow can be done with X-ray to monitor defects such as bridging, open circuits and voids.

14.3.3 Rework

In general, rework is not recommended. By rework we mean the process of removing the chip from the substrate and replacing it with a new chip. If a chip is removed from the substrate, most solder balls of the chip will be damaged. In that case it is recommended not to re-use the chip again.

Device removal can be done when the substrate is heated until it is certain that all solder joints are molten. The chip can then be carefully removed from the substrate without damaging the tracks and solder lands on the substrate. Removing the device must be done using plastic tweezers, because metal tweezers can damage the silicon. The

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surface of the substrate should be carefully cleaned and all solder and flux residues and/ or underfill removed. When a new chip is placed on the substrate, use the flux process instead of solder on the solder lands. Apply flux on the bumps at the chip side as well as on the solder pads on the substrate. Place and align the new chip while viewing with a microscope. To reflow the solder, use the solder profile shown in application note *AN10365 "Surface mount reflow soldering description"*.

14.3.4 Cleaning

Cleaning can be done after reflow soldering.

15 Revision history

Table 11. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
TFA9874B_SDS v.1	20180814	Product data sheet	-	-	

16 Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] [3] The term 'short data sheet' is explained in section "Definitions".

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